

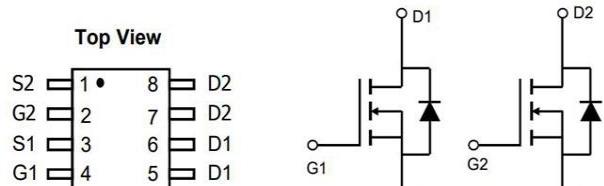
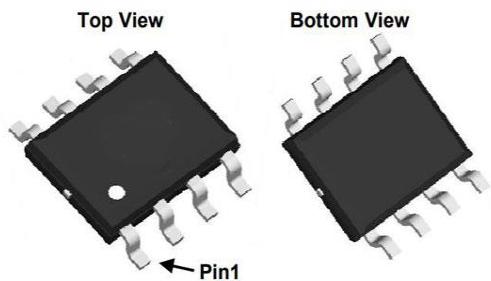
40V /6A Dual 2N Power MOSFET
General Description

40V /6A Dual 2N Power MOSFET

Very low on-resistance RDS(on) @ VGS=4.5 V

Pb-free lead plating; RoHS compliant

V_{DS}	40	V
R_{DS(on),TYP@VGS=10V}	26.6	mΩ
R_{DS(on),TYP@VGS=4.5}	41.8	mΩ
I_D	6	A



Part ID	Package Type	Marking	Tape and reel infomation
SM4840PRL	SOP8	4840	3000


 100% UIS Tested
100% RG Tested

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V _{DS}	40	V
Gate-Source Voltage	V _{GS}	20	±V
Continuous Drain Current A TA=25°C	I _D	6.0	A
TA=70°C	I _D	5.0	
Pulsed Drain Current B	I _{DM}	9.6	
Avalanche Current G	I _{AR}	1.9	
Repetitive avalanche energy L=0.1mH G	E _{AR}	4.4	mJ
Power Dissipation A TA=25°C	P _D	2	W
TA=70°C	P _D	1.3	
Junction and Storage Temperature Range	T _J , T _{STG}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient A	R _{θJA}	95	142	°C/W
Maximum Junction-to-Ambient A Steady State		190	228	°C/W
Maximum Junction-to-Lead c Steady State	R _{θJL}	57	91	°C/W

STATIC PARAMETERS

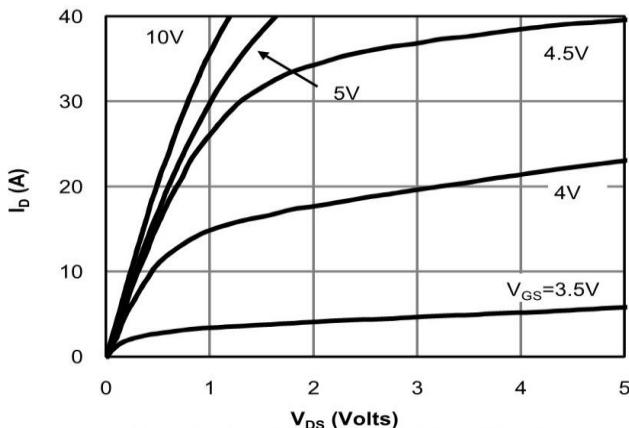
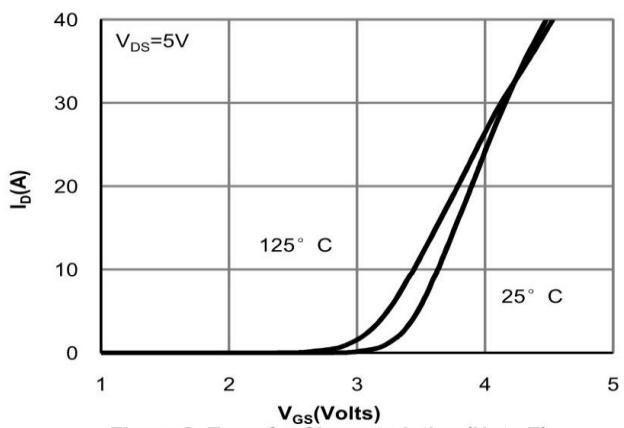
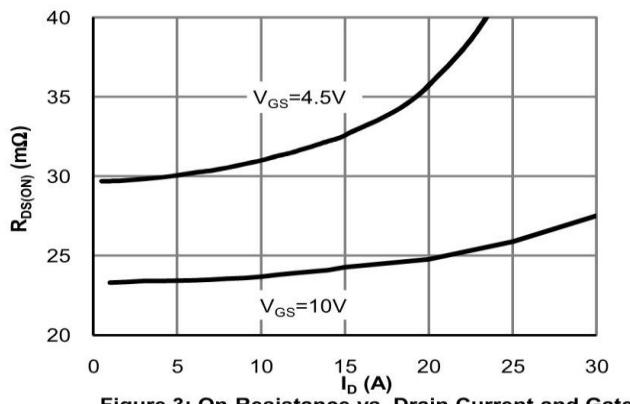
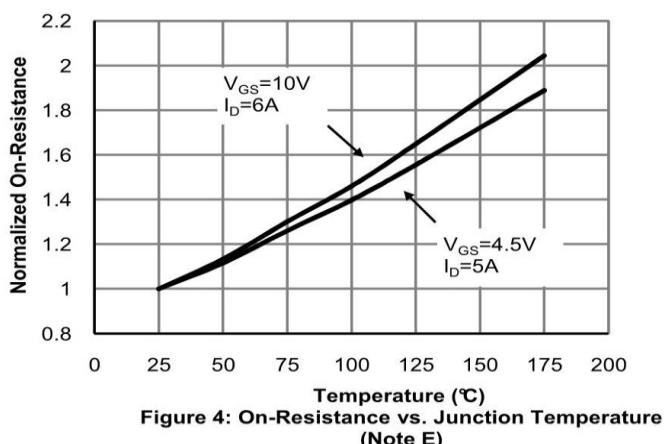
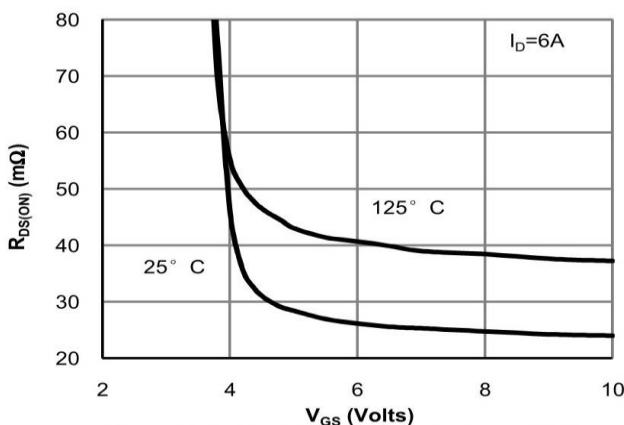
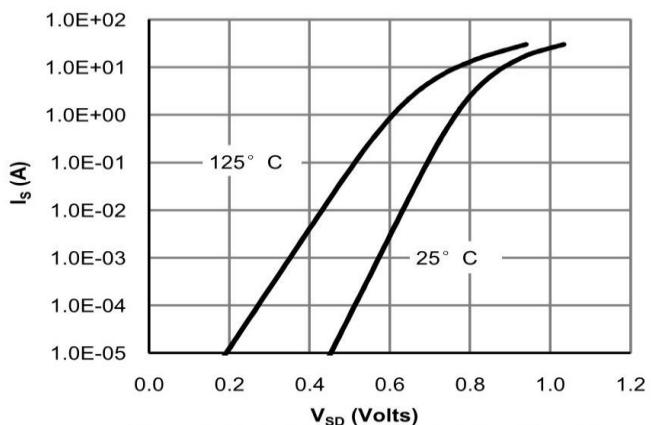
Symbol	Parameter	Conditions	Min	Typ	Max	Units
BV_{DSS}	Drain-Source Breakdown Voltage	$I_D = -250\mu A, V_{GS} = 0V$	40			V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=40V, V_{GS}=0V$			1	uA
					5	
I_{GSS}	Gate-Body leakage current	$V_{DS} = 0V, V_{GS} = \pm 20V$			± 100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.5	2.3	3	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance	$V_{GS}=-10V, I_D=6A$		26.6	38.0	$m\Omega$
		$V_{GS}=4.5V, I_D=6A$		41.8	54.3	
g_{FS}	Forward Transconductance	$V_{DS}=5V, I_D=6A$		89		S
V_{SD}	Diode Forward Voltage	$I_S=1A, V_{GS}=24V$		0.72	1	V
I_S	Maximum Body-Diode Continuous Current				6	A

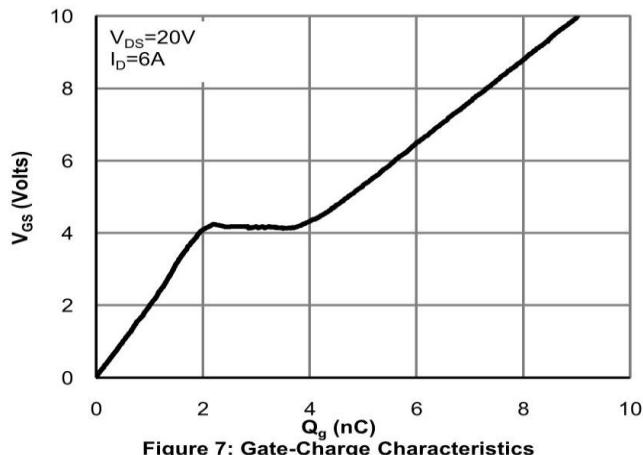
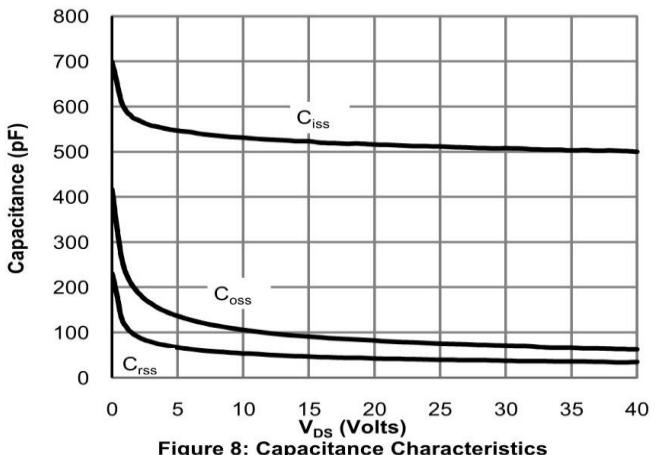
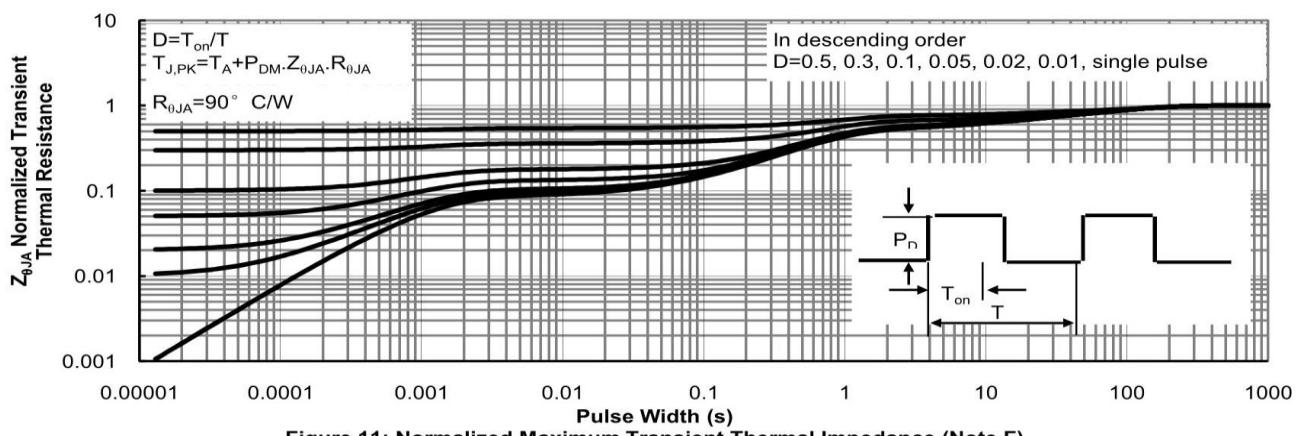
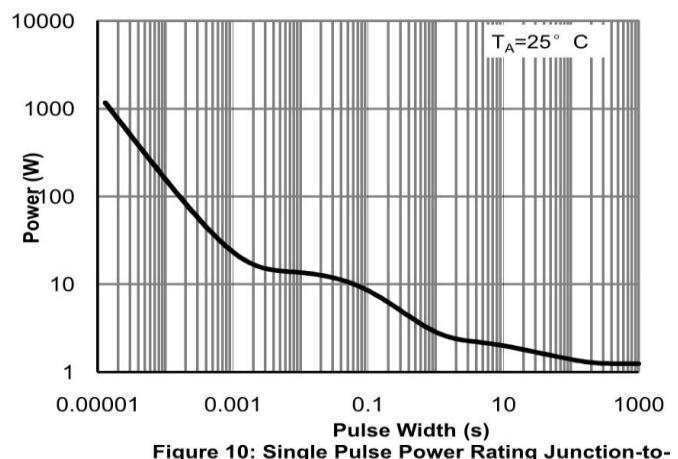
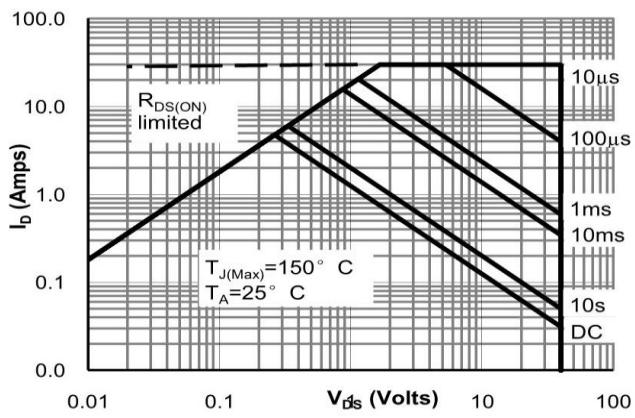
DYNAMIC PARAMETERS

Symbol	Parameter	Conditions	Min	Typ	Max	Units
C_{iss}	Input Capacitance	$V_{GS}=0V, V_{DS}=15V, f=1MHz$		516	629	pF
C_{oss}	Output Capacitance			82	100	pF
C_{rss}	Reverse Transfer Capacitance			43	51	pF
R_g	Gate resistance	$V_{GS}=0V, V_{DS}=0V, f=1MHz$			0.7	Ω

SWITCHING PARAMETERS

Symbol	Parameter	Conditions	Min	Typ	Max	Units
$Q_g(10V)$	Total Gate Charge	$V_{GS}=10V, V_{DS}=15V, I_D=6A$		4.3		nC
$Q_g 4.5V)$	Total Gate Charge			2.15		
Q_{gs}	Gate Source Charge			0.98		
Q_{gd}	Gate Drain Charge			1.4		
$t_{D(on)}$	Turn-On Delay Time	$V_{GS}=10V, V_{DS}=15V, RL=0.75\Omega, R_{GEN}=3\Omega$		9		ns
t_r	Turn-On Rise Time			7.2		
$t_{D(off)}$	Turn-Off Delay Time			25.2		
t_f	Turn-Off Fall Time			8.1		
t_{rr}	Body Diode Reverse Recovery Time	$I_F=-8A, dI/dt=500A/\mu s$		18		ns
Q_{rr}	Body Diode Reverse Recovery Charge	$I_F=18A, dI/dt=500A/\mu s$		10		nC

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Fig 1: On-Region Characteristics (Note E)

Figure 2: Transfer Characteristics (Note E)

Figure 3: On-Resistance vs. Drain Current and Gate Voltage (Note E)

Figure 4: On-Resistance vs. Junction Temperature (Note E)

Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

Figure 6: Body-Diode Characteristics (Note E)

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Figure 7: Gate-Charge Characteristics

Figure 8: Capacitance Characteristics


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